

Specification Sheet

SOI Wafer N Type

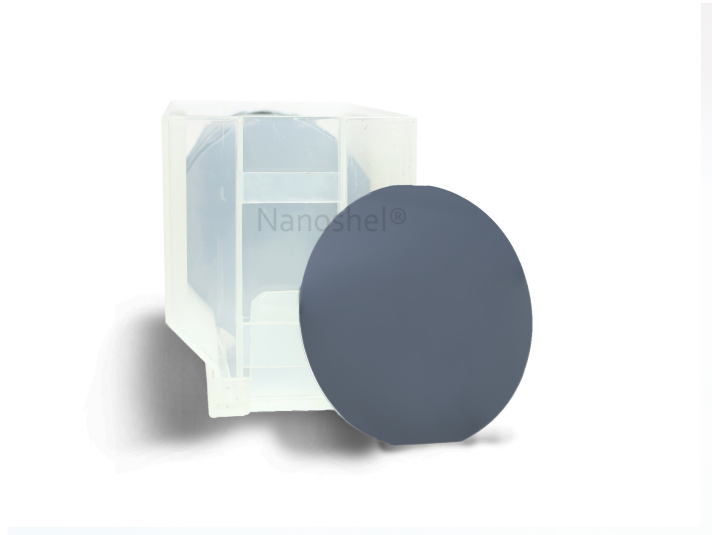
(Purity: 99.9% Dia: 4”(100mm) CZ Thickness: 450μm)

Stock No: NS6130-10-1308, CAS: 7440-21-3

Product	:	SOI Wafer 4” N Type
Stock No	:	NS6130-10-1308
CAS	:	7440-21-3
Diameter	:	4”
Thickness	:	450μm
Dopant	:	Phosphorus
Crystal Orientation	:	< 100>
Type	:	n- Type
Growth Method	:	CZ
Resistivity	:	1-10Ω.cm
Edge Profile	:	Rounded
Front Surface	:	Polished
Back Surface	:	Etched
Main Inspect Verifier	:	Manager QC

Note: Product Specification are subject to amendment and may change over time

Characterization of SOI Wafer N Type



SOI Wafer N Type



NANOSHEL
Creating Miracles in Black